

Application Note AN-1113

IRS2301 and IR2301 Comparison

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Introduction

The IRS2301 is a new HVIC product that replaces the IR2301 HVICs and is pin-to-pin compatible with its corresponding predecessor. In many cases, little or no change is necessary to use the new products. This application note describes the various differences between the IRS2301 and the IR2301 HVICs.

The IRS2301 is a high voltage, high speed power MOSFET and IGBT driver with independent high and low side referenced output channels. Proprietary HVIC and latch immune CMOS technologies enable ruggedized monolithic construction. The logic input is compatible with standard CMOS or LSTTL output, down to 3.3 V logic. The output driver features a high pulse current buffer stage designed for minimum driver cross-conduction. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high side configuration which operates up to 600 V.

Dynamic Electrical Characteristics

Parameter		IR2301		IRS2301		Units
Symbol	Definition	typ	max	typ	max	
t_r	Turn-on rise time ($V_s = 0\text{ V}$)	130	220	100	220	ns
t_f	Turn-off fall time ($V_s = 0\text{ V}$)	50	80	35	80	

The IRS2301 has faster rise and fall times when compared to the IR2301.

Static Electrical Characteristics

Parameter		IR2301			IRS2301			Units
Symbol	Definition	min	typ	max	min	typ	max	
V_{IH}	Logic "1" input voltage	2.9	-	-	2.5	-	-	V
V_{IL}	Logic "0" input voltage	-	-	0.8	-	-	0.8	
V_{OH}	High level output voltage, $V_{BIAS} - V_O$	-	0.8	1.4	-	0.05	0.2	
		I _O = 20 mA			I _O = 2 mA			
V_{OL}	Low level output voltage, V_O	-	0.3	0.6	-	0.02	0.1	
		I _O = 20 mA			I _O = 2 mA			
I_{O+}	Output high short circuit pulsed current ($V_O = 0\text{ V}$, $V_{IN} = \text{Logic "1"}$, $PW \leq 10\mu\text{s}$)	120	200	-	120	290	-	mA
I_{O-}	Output low short circuit pulsed current ($V_O = 15\text{ V}$, $V_{IN} = \text{Logic "0"}$, $PW \leq 10\mu\text{s}$)	250	350	-	250	600	-	

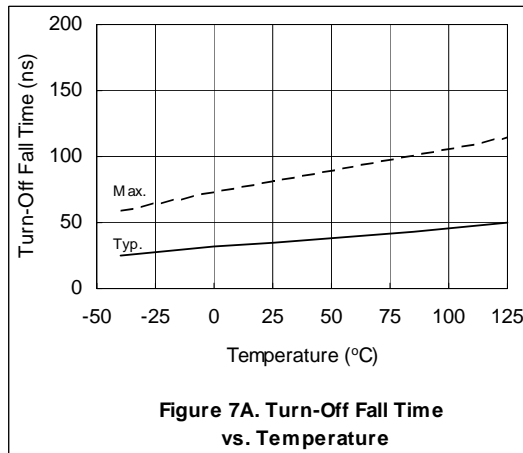
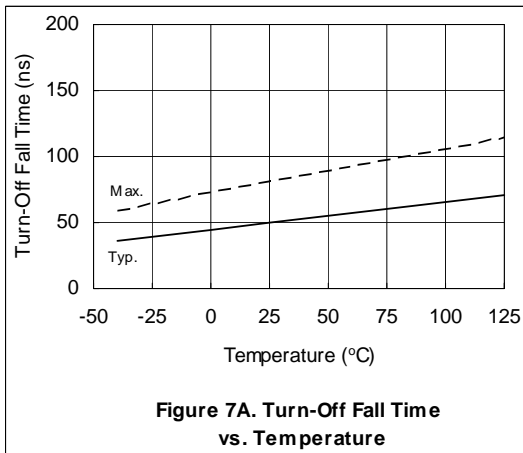
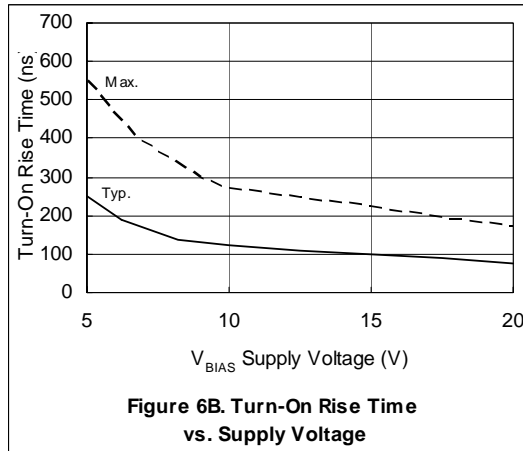
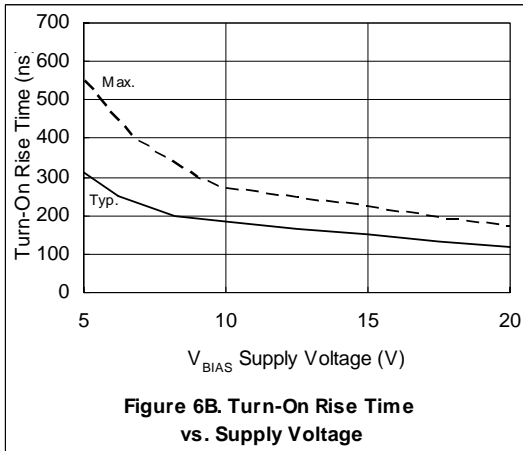
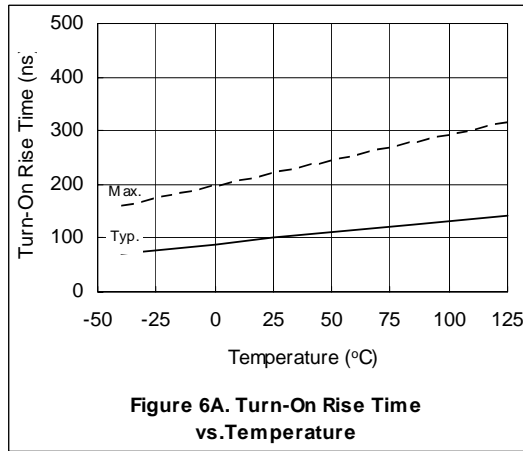
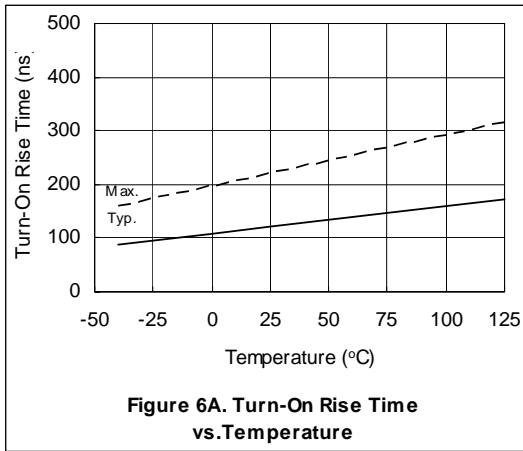
With the IRS2301,

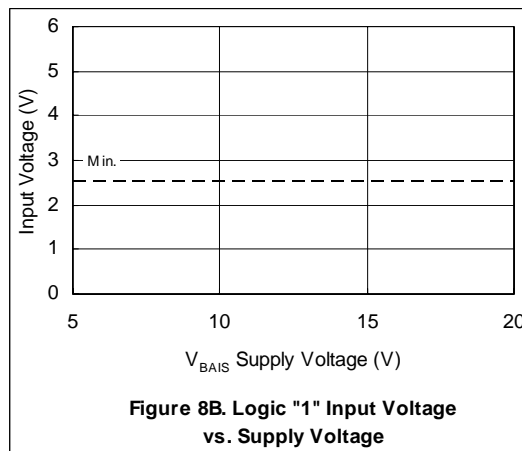
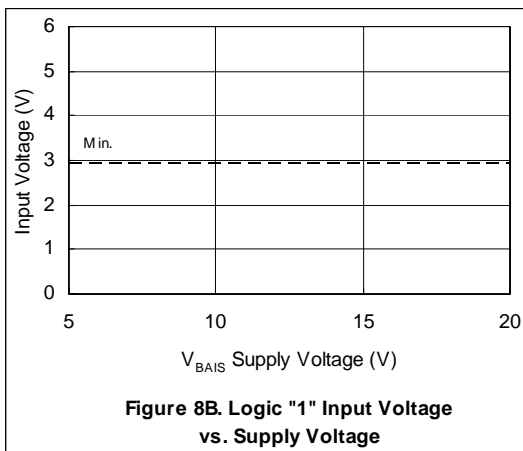
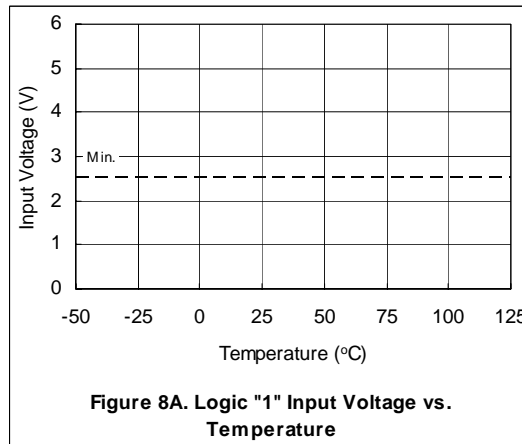
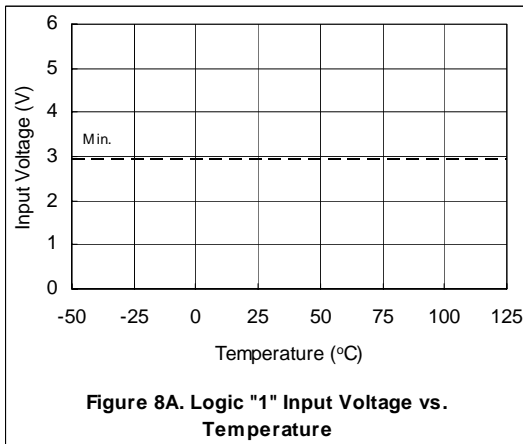
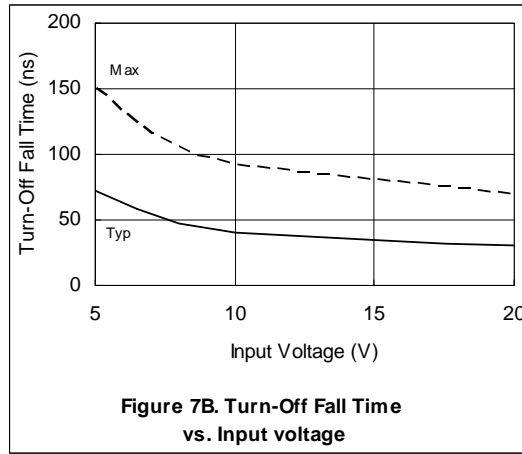
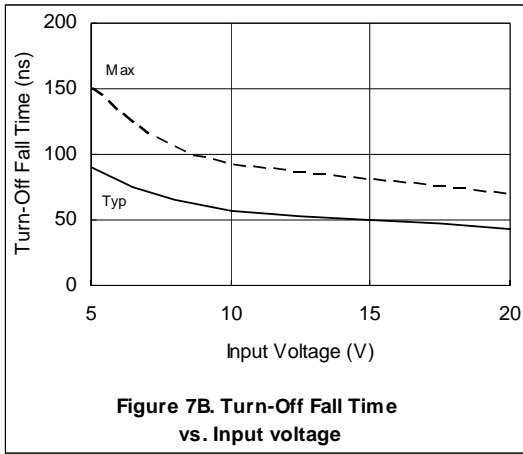
1. The V_{IH} has been reduced to 2.5 V for better 3.3 V logic compatibility.
2. The V_{OH} and V_{OL} are tested using a new standardized test condition of $I_{O} = 2\text{ mA}$. The output driver's on resistance is slightly lower for IRS2301.
3. The typical values for I_{O+} and I_{O-} are higher, which allows faster switching.

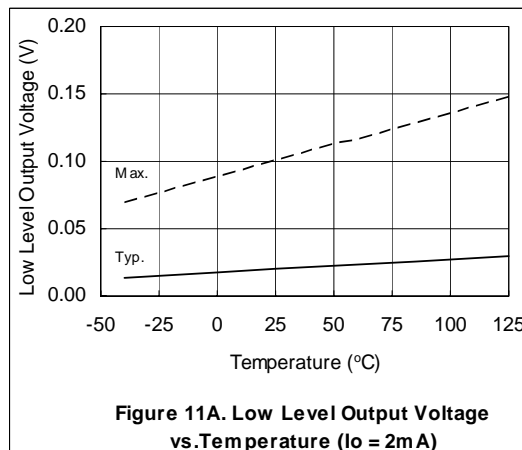
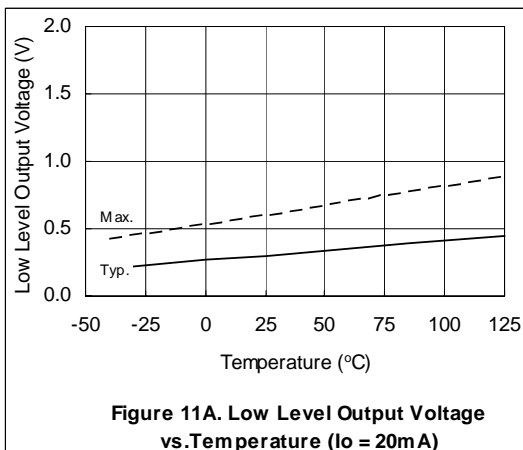
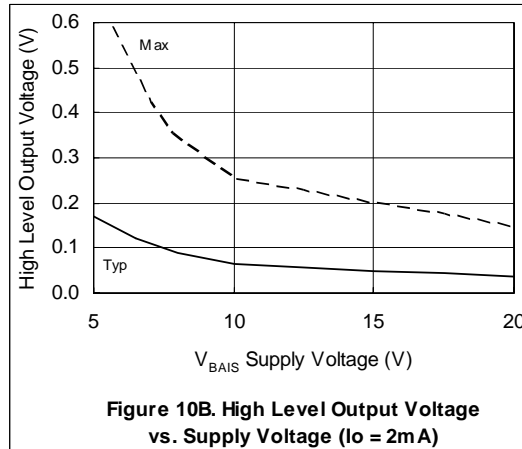
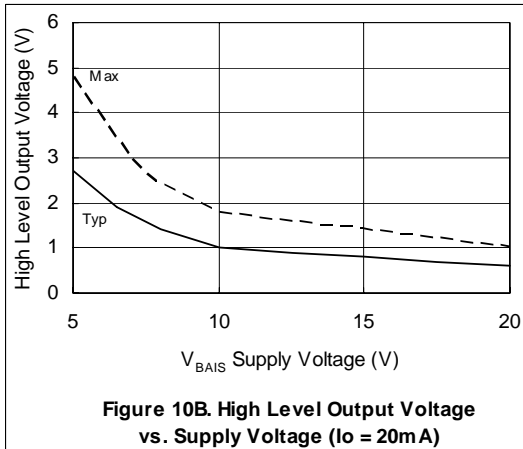
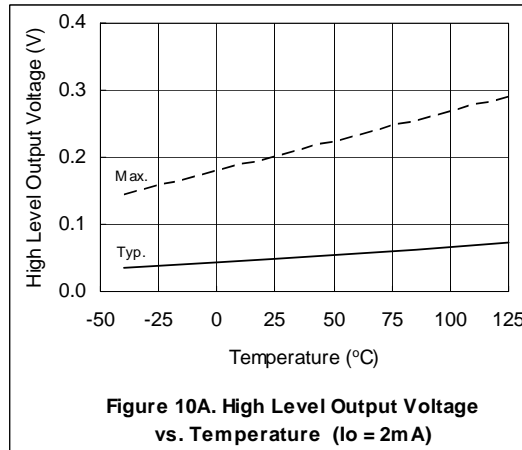
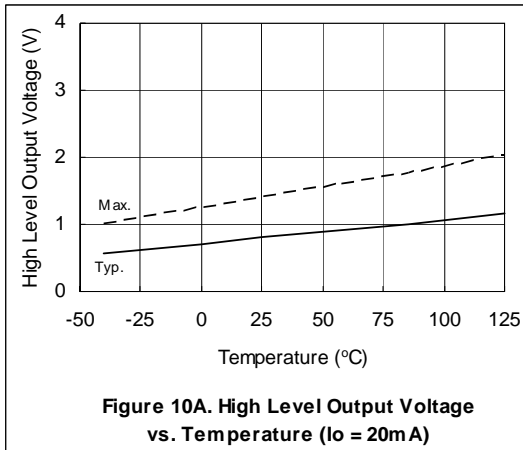
Figures

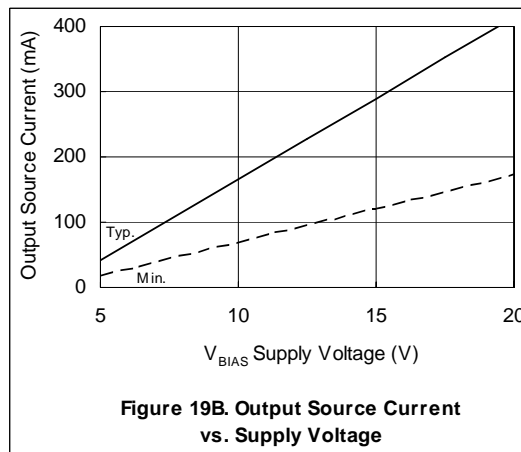
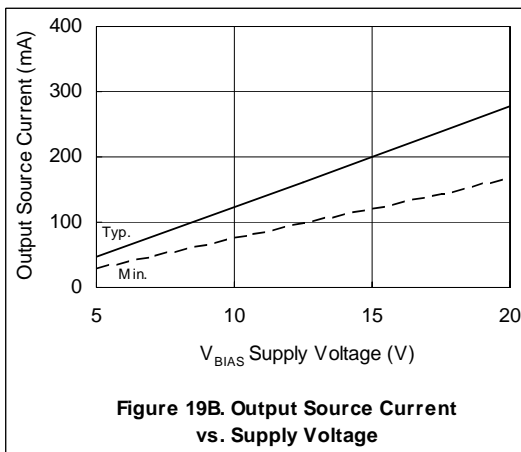
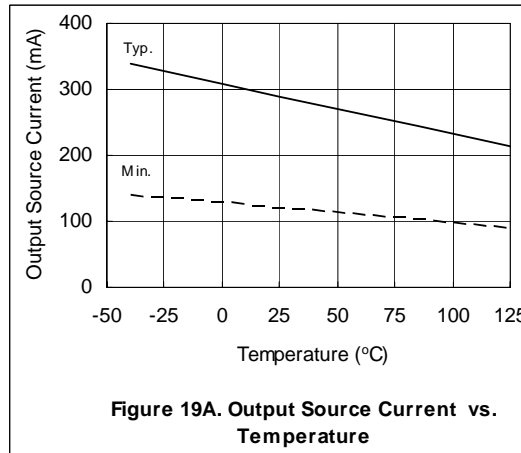
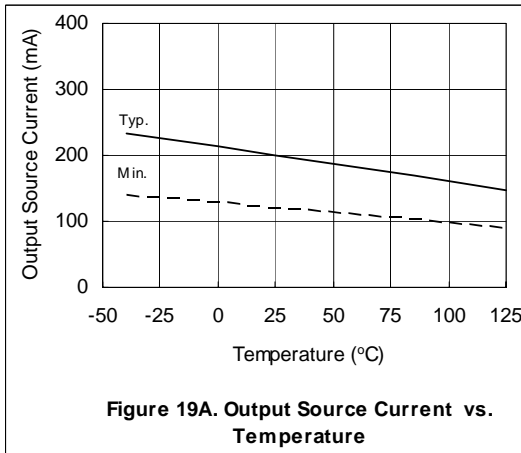
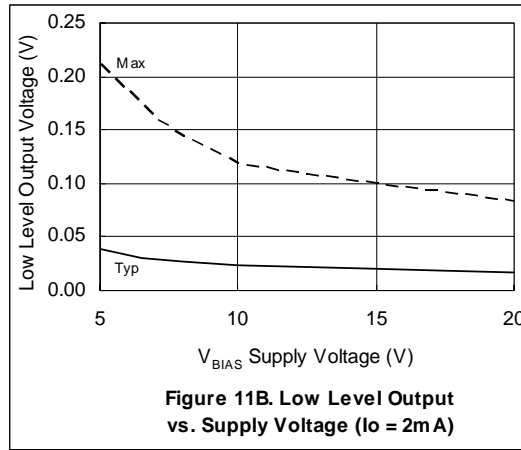
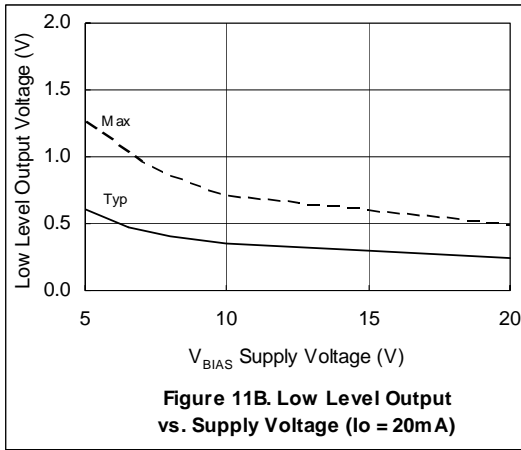
This figures shown in this section compare figures shown in the IR2301 (left column) and IRS2301 (right column) datasheets. Illustrations that have not changed between the two datasheets have not been included in this section.

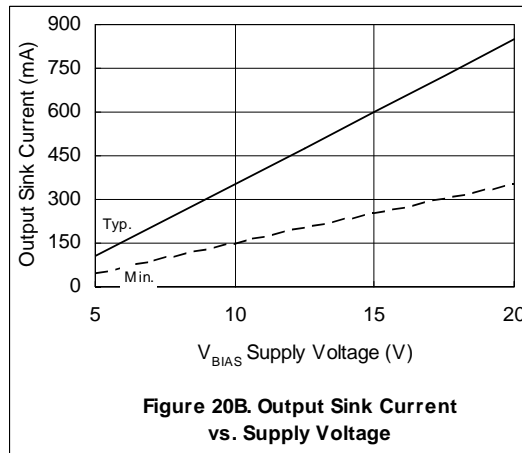
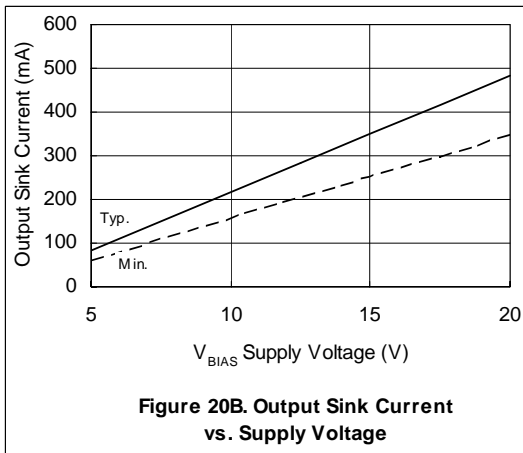
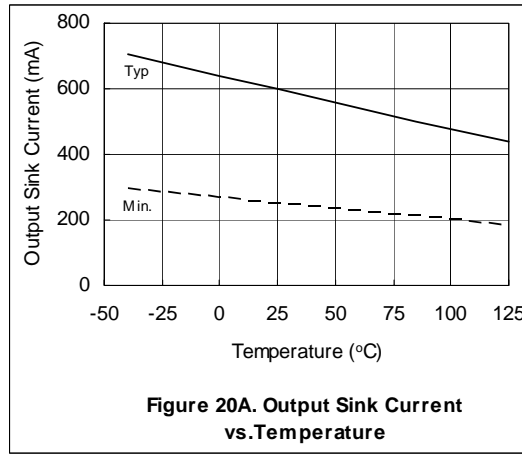
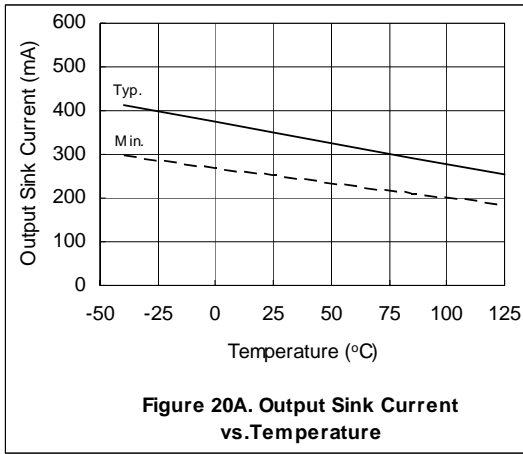
IR2301	IRS2301
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Summary

As shown by this document, the IRS2301 and the IR2301 are very similar with only a few parametric differences.